Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.41$ V at $I_F = 5$ A



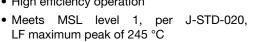
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PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 7.5 A				
V _{RRM}	45 V				
I _{FSM}	100 A				
V_F at $I_F = 7.5 A$	0.49 V				
T _{OP} max. (AC mode)	150 °C				
T _J max. (DC forward current)	200 °C				
Package	D ² PAK (TO-263AB)				
Circuit configurations	Common cathode				

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation



RoHS

COMPLIANT

- T_J 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: D²PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER			VBT1545CBP	UNIT		
Maximum repetitive peak reverse voltage		V _{RRM}	45	V		
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)} ⁽¹⁾	15	А		
Maximum average forward rectified current (lig. 1)	per diode	'F(AV)	7.5			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			100	А		
Operating junction and storage temperature range (AC mode)			-40 to +150	°C		
Junction temperature in DC forward current without reverse bias, $t \leq 1 \ h$		T _J ⁽²⁾	≤ 200	°C		

Notes

⁽¹⁾ With heatsink

⁽²⁾ Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST C	TEST CONDITIONS		TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.49	-	v
	I _F = 7.5 A	$I_A = 25$ C		0.55	0.63	
	I _F = 5 A	T _A = 125 °C		0.41	-	
	I _F = 7.5 A			0.49	0.57	
Reverse current per diode		T _A = 25 °C	I _R ⁽²⁾	-	500	μA
	V _R = 45 V	T _A = 125 °C		5	15	mA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

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THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VBT1545CBP	UNIT	
Typical thermal resistance	per diode	$R_{ extsf{ heta}JC}$	3.5	°C/W	
Typical mermanesistance	per device		2.5		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT1545CBP-E3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VBT1545CBP-E3/8W	1.38	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

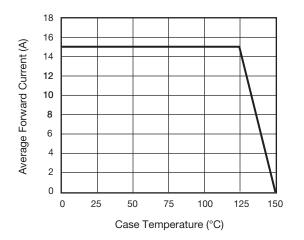


Fig. 1 - Maximum Forward Current Derating Curve

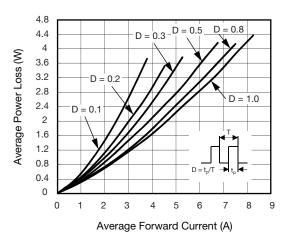
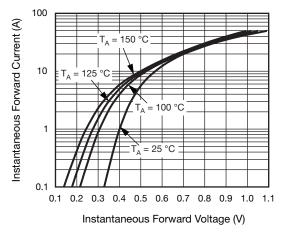


Fig. 2 - Forward Power Loss Characteristics Per Diode





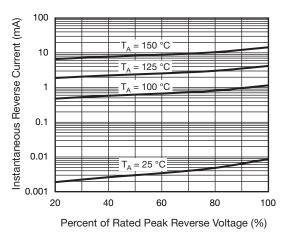


Fig. 4 - Typical Reverse Characteristics Per Diode

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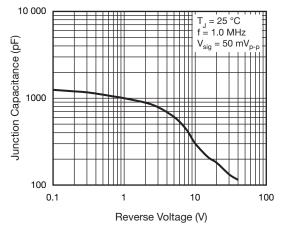
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Fig. 5 - Typical Junction Capacitance Per Diode

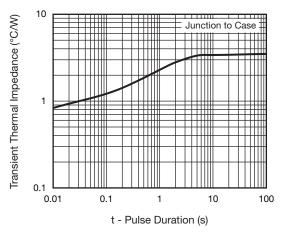
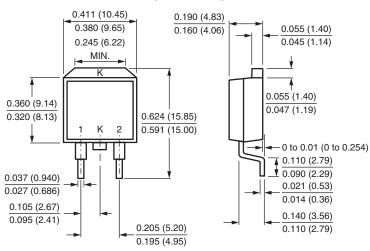


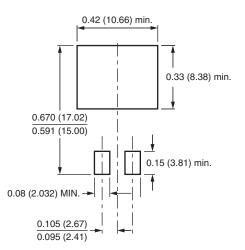
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



D²PAK (TO-263AB)

Mounting Pad Layout



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 3
 Document Number: 89486

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